CONFIDENTIAL BUSINESS INFORMATION – SUBJECT TO PROTECTIVE ORDER

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UNITED STATES INTERNATIONAL TRADE COMMISSION
Washington, D.C. 20436

Before the Honorable Bryan F. Moore
Administrative Law Judge

In the Matter of **CERTAIN SENSORS WITH PIXELS AND PRODUCTS CONTAINING THE SAME**	**Investigation No. 337-TA-1403**

OPENING EXPERT REPORT OF DR. ADAM FONTECCHIO REGARDING UNITED STATES PATENT NO. 11,069,737 (January 31, 2025)

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